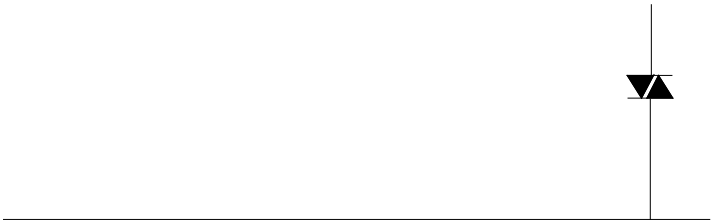
Average gate power dissipation (T_j=125)	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	10	W
Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.7)	V_{pp}	2	kV

[redacted]

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



ACJT810-10A

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